



# **BSS84**

### **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(on)</sub> max	<b>Ι</b> <sub>D</sub> Τ <sub>A</sub> = +25°C
-50V	10Ω @ V <sub>GS</sub> = -5V	-130mA

# **Description and Applications**

This MOSFET has been designed to minimize on-state resistance (R<sub>DS(on)</sub>) and yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

- General Purpose Interfacing Switch
- **Power Management Functions**
- Analog Switch

# P-CHANNEL ENHANCEMENT MODE MOSFET

#### Features and Benefits

- Low On-Resistance •
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e.: parts gualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please refer to the related automotive grade (Q-suffix) part. A listing can be found at

https://www.diodes.com/products/automotive/automotiveproducts/.

This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.

https://www.diodes.com/guality/product-definitions/

An Automotive-Compliant Part is Available Under Separate Datasheet (BSS84Q)

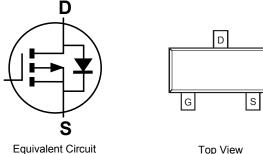
### **Mechanical Data**

- Case: SOT23 (Standard)
- Case Material: UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish (Lead Free Plating) Solderable per MIL-STD-202, Method 208 @3)
- Terminal Connections: See Diagram
- Weight: 0.009 grams (Approximate)



SOT23

Top View



Top View

#### Ordering Information (Note 4)

Part Number	Case	Packaging
BSS84-7-F	SOT23 (Standard)	3000/Tape & Reel
BSS84-13-F	SOT23 (Standard)	10000/Tape & Reel

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. Notes:

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2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



### **Marking Information**



K84 = Product Type Marking Code YM = Date Code Marking Y or  $\overline{Y}$  = Year (ex: I = 2021) M or  $\overline{M}$  = Month (ex: 9 = September)

Date Code Key												
Year	1998		2021	2022	2023	2024	2025	2026	2027	2028	2029	2030
Code	J			J	K	L	М	N	0	Р	R	S
Month	Jan	Feb	Mar	Apr	Mav	Jun	Jul	Aug	Sep	Oct	Nov	Dec

# Maximum Ratings (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Drain-Source Voltage		V <sub>DSS</sub>	-50	V
Drain-Gate Voltage $R_{GS} \le 20 k\Omega$		V <sub>DGR</sub>	-50	V
Gate-Source Voltage	Continuous	V <sub>GSS</sub>	±20	V
Drain Current (Note 5)	Continuous	ID	-130	mA
Pulsed Drain Current		I <sub>DM</sub>	-1.2	A

# Thermal Characteristics (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 5)	PD	300	mW
Thermal Resistance, Junction to Ambient	R <sub>0JA</sub>	417	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

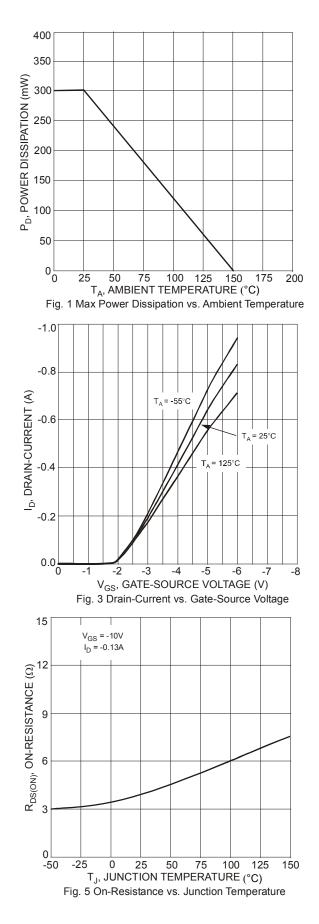
### Electrical Characteristics (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

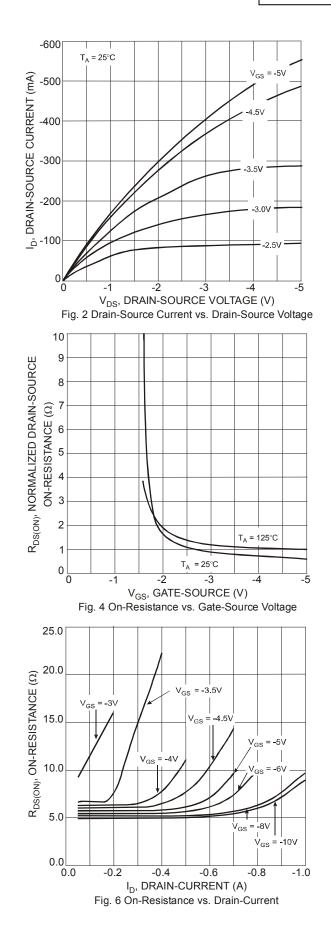
Characteristic	Symphol	Min	T <sub>1</sub> m	Max	فتعال	Test Condition	
Characteristic	Symbol	Min	Тур	Мах	Unit	Test Condition	
OFF CHARACTERISTICS (Note 6)							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	-50	_	_	V	$V_{GS} = 0V, I_D = -250\mu A$	
		—		-1	μA	V <sub>DS</sub> = -50V, V <sub>GS</sub> = 0V, T <sub>J</sub> = +25°C	
Zero Gate Voltage Drain Current	IDSS	—	—	-2	μA	V <sub>DS</sub> = -50V, V <sub>GS</sub> = 0V, T <sub>J</sub> = +125°C	
		_	_	-100	nA	$V_{DS}$ = -25V, $V_{GS}$ = 0V, $T_{J}$ = +25°C	
Gate-Body Leakage	I <sub>GSS</sub>	_	_	±10	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 6)							
Gate Threshold Voltage	V <sub>GS(th)</sub>	-0.8	_	-2.0	V	$V_{DS} = V_{GS}$ , $I_D = -1mA$	
Static Drain-Source On-Resistance	R <sub>DS(on)</sub>	_	3.2	10	Ω	V <sub>GS</sub> = -5V, I <sub>D</sub> = -0.100A	
Forward Transconductance	<b>g</b> fs	0.05	_	_	S	V <sub>DS</sub> = -25V, I <sub>D</sub> = -0.1A	
DYNAMIC CHARACTERISTICS (Note 7)							
Input Capacitance	Ciss	_	24.6	45	pF		
Output Capacitance	Coss	_	4.7	25	pF	V <sub>DS</sub> = -25V, V <sub>GS</sub> = 0V, f = 1.0MHz	
Reverse Transfer Capacitance	Crss	_	2.8	12	pF		
Gate Resistance	Rg		916		Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge (V <sub>GS</sub> = -4.5V)	Qg		0.28		nC		
Total Gate Charge (V <sub>GS</sub> = -10V)	Qg	_	0.59	_	nC	1/2 = 10/2 = 0.10	
Gate-Source Charge	Qgs	_	0.09	_	nC	V <sub>DS</sub> = -10V, I <sub>D</sub> = -0.1A	
Gate-Drain Charge	Q <sub>gd</sub>		0.08	_	nC		
Turn-On Delay Time	t <sub>D(on)</sub>		10		ns	V <sub>DD</sub> = -30V, I <sub>D</sub> = -0.27A,	
Turn-Off Delay Time	t <sub>D(off)</sub>		18	_	ns	$R_{GEN} = 50\Omega, V_{GS} = -10V$	

5. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown in Diodes Incorporated's package outline PDFs, which can be found Notes: on our website at http://www.diodes.com/package-outlines.html.

6. Short duration pulse test used to minimize self-heating effect.
7. Guaranteed by design. Not subject to production testing.



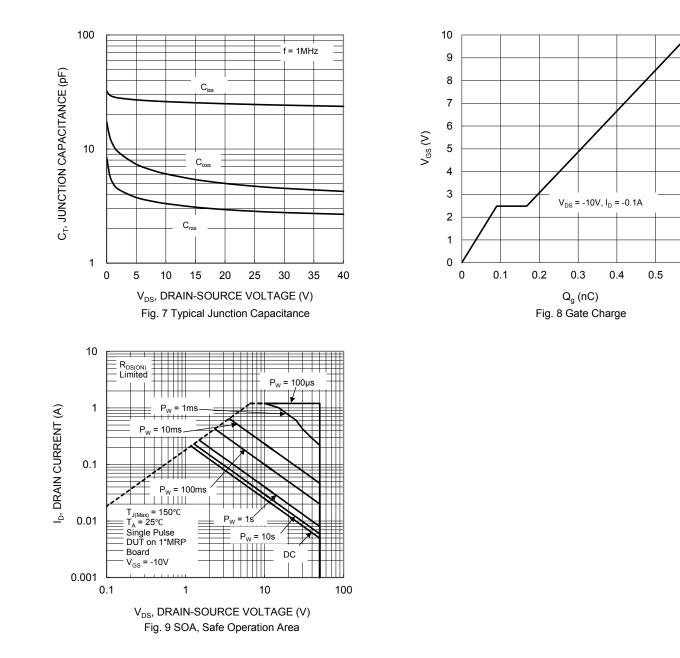




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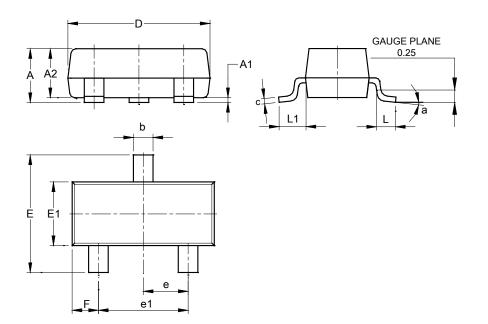
0.6





# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.



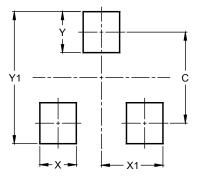
S	SOT23 (Standard)							
Dim	Min	Max	́Тур					
Α	0.90	1.15	1.025					
A1	0.00	0.10	0.05					
A2	0.85	1.10	0.975					
b	0.30	0.51	0.40					
С	0.080	0.202	0.11					
D	2.80	3.00	2.90					
E	2.25	2.55	2.40					
E1	1.20	1.40	1.30					
е	0.89	1.03	0.915					
e1	1.78	2.05	1.83					
F	0.40	0.60	0.535					
L1	0.45	0.61	0.55					
L	0.25	0.55	0.40					
а	0°	8°						
All	All Dimensions in mm							

### Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### SOT23 (Standard)

SOT23 (Standard)



Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Y	0.9
Y1	2.9

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